# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







\*G Denotes RoHS Compliant, Pb Free Terminal Finish.

## ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

#### PRODUCT APPLICATIONS

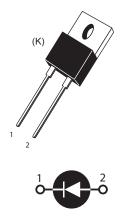
- Anti-Parallel Diode
  -Switchmode Power Supply
  -Inverters
- Free Wheeling Diode
  -Motor Controllers
  -Converters
  -Inverters
- Snubber Diode
- PFC

#### PRODUCT FEATURES

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- Popular TO-220 Package
- Low Forward Voltage
- Low Leakage Current
- Avalanche Energy Rated

#### PRODUCT BENEFITS

- Low Losses
- · Low Noise Switching
- Cooler Operation
- · Higher Reliability Systems
- Increased System Power Density



1 - Cathode 2 - Anode Book of Copp. Cath

All Ratings:  $T_c = 25^{\circ}C$  unless otherwise specified.

Back of Case - Cathode

#### MAXIMUM RATINGS

			•
Symbol	Characteristic / Test Conditions	APT30DQ100K(G)	UNIT
V <sub>R</sub>	Maximum D.C. Reverse Voltage		
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage	1000	Volts
V <sub>RWM</sub>	Maximum Working Peak Reverse Voltage		
I <sub>F(AV)</sub>	Maximum Average Forward Current (T <sub>C</sub> = 102°C, Duty Cycle = 0.5)	30	
I <sub>F(RMS)</sub>	RMS Forward Current (Square wave, 50% duty)	43	Amps
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current ( $T_J = 45^{\circ}C$ , 8.3ms)	150	
E <sub>AVL</sub>	Avalanche Energy (1A, 40mH)	20	mJ
T <sub>J</sub> ,T <sub>STG</sub>	Operating and StorageTemperature Range	-55 to 175	°O
Τ <sub>L</sub>	Lead Temperature for 10 Sec.	300	°C

#### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		MIN	TYP	MAX	UNIT
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 30A		2.5	3.0	Volts
		I <sub>F</sub> = 60A		3.06		
		I <sub>F</sub> = 30A, T <sub>J</sub> = 125°C		1.92		
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> = 1000V			100	μA
		V <sub>R</sub> = 1000V, T <sub>J</sub> = 125°C			500	
CT	Junction Capacitance, V <sub>R</sub> = 200V			26		pF

#### DYNAMIC CHARACTERISTICS

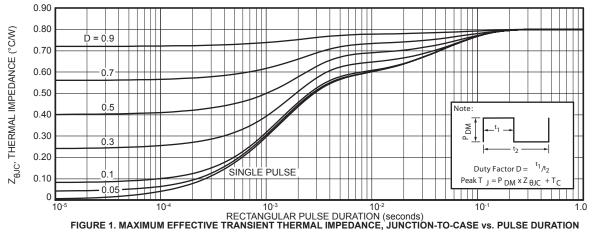
#### APT30DQ100K(G)

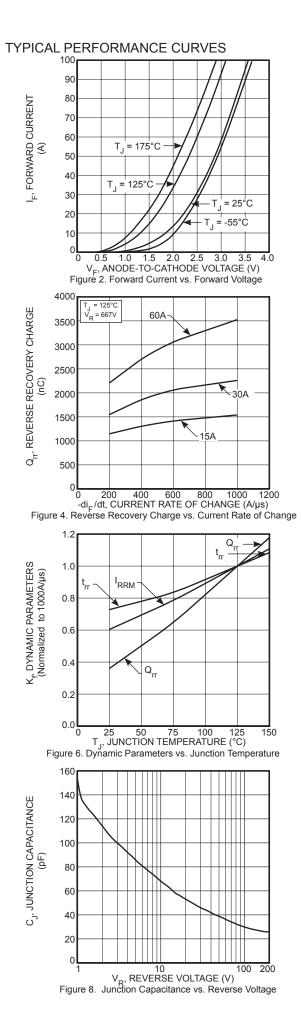
Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
t <sub>rr</sub>	Reverse Recovery Time $I_F = 1A, di_F/dt =$	-100A/μs, V <sub>R</sub> = 30V, T <sub>J</sub> = 25°C	-	24		nc
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 30A, di <sub>F</sub> /dt = -200A/μs V <sub>R</sub> = 667V, T <sub>C</sub> = 25°C	-	295		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	440		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	4	-	Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 30A, di <sub>F</sub> /dt = -200A/μs V <sub>R</sub> = 667V, T <sub>C</sub> = 125°C	-	330		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	1550		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	8	-	Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 30A, di <sub>F</sub> /dt = -1000A/µs V <sub>R</sub> = 667V, T <sub>C</sub> = 125°C	-	150		ns
Q <sub>rr</sub>	Reverse Recovery Charge		-	2250		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current		-	25		Amps

#### THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
R <sub>θJC</sub>	Junction-to-Case Thermal Resistance			.80	°C/W
W <sub>T</sub>	Package Weight		0.07		οz
			1.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

Microsemi reserves the right to change, without notice, the specifications and information contained herein.





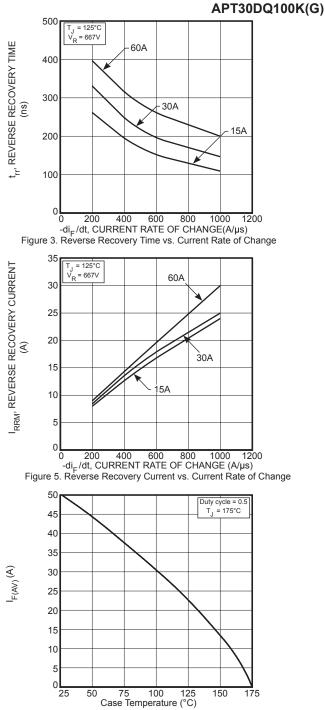
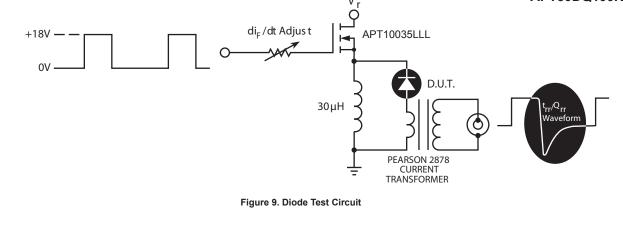
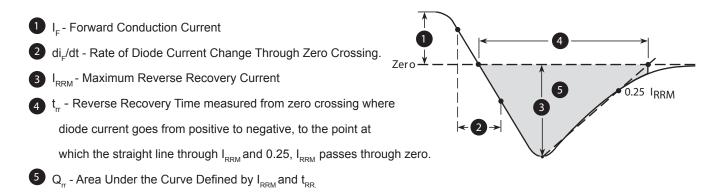
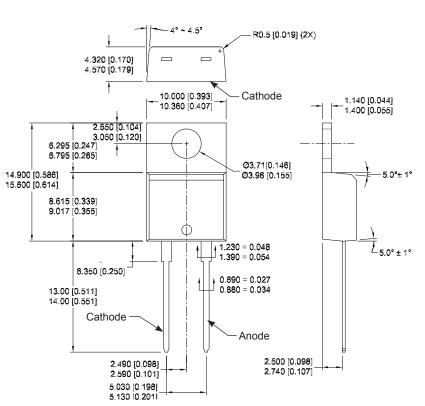


Figure 7. Maximum Average Forward Current vs. CaseTemperature





#### Figure 10. Diode Reverse Recovery Waveform Definition



### TO-220 (K) Package Outline

e3 100% Sn



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